



High-Speed, Low R_{ON}, SPDT Analog Switch

(2:1 Multiplexer/Demultiplexer Bus Switch)

DESCRIPTION

The DG3157 is a high-speed single-pole double-throw, low power, TTL-Compatible bus switch. Using sub-micro CMOS technology, the DG3157 achieves low on-resistance and negligible propagation delay.

The DG3157 can handle both analog and digital signals and permits signals with amplitudes of up to V_{CC} to be transmitted in either direction.

When the Select pin is low, B_0 is connected to the output A pin. When the Select pin is high, B_1 is connected to the output A pin. The path that is open will have a high-impedance state with respect to the output. Make-before-break is guaranteed. An eptiaxial layer prevents latch-up.

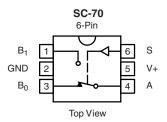
FEATURES

- Halogen-free According to IEC 61249-2-21
- Direct cross to industry standard SN74LVC1G3157, NC7SB3157, NLASB3175, PI5A3157, and STG3157
- SC-70 6-lead package
- 1.65 V to 5.5 V V_{CC} operation
- 5 Ω connection between ports
- Minimal propagation delay
- · Break-before-make switching
- Zero bounce in flow-through mode



ROHS COMPLIANT HALOGEN FREE

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device Marking: G1

TRUTH TABLE	
Logic Input (S)	Function
0	B ₀ Connected to A
1	B ₁ Connected to A

ORDERING INFORMATION						
Temp. Range	Package	Part Number				
- 40 °C to 85 °C	SC-70-6	DG3157DL-T1-E3 DG3157DL-T1-GE3 (Halogen-free)				

Vishay Siliconix

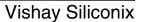


ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Reference V+ to GND		- 0.3 to + 6	V			
S, A, B ^a	- 0.3 to (V+ + 0.3)	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				
Continuous Current (Any terminal)		± 50	mA			
Peak Current (Pulsed at 1 ms, 10 % duty of	ycle)	± 200	IIIA			
Storage Temperature	D Suffix	- 65 to 150	°C			
Power Dissipation (Packages) ^b	6-Pin SC-70 ^c	250	mW			

Notes:

- a. Signals on A, or B or S exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 3.1 mW/°C above 70 °C.

SPECIFICATIONS								
		Test Conditions Unless Otherwise Specified			- 4	5 °C		
Parameter	Symbol	V+ = 3.0 V, \	$V_{\rm S} = 0.25 \text{ V to } 0.7 \text{ V+}^{\rm e}$	Temp.a	Min.b	Typ. ^c	Max.b	Unit
DC Characteristics								
High Level Input Voltage	V _{SH}	V+ =	1.65 to 1.95 V	Full	0.75 V+			
Tilgit Level input voltage	*511	V+ :	= 2.3 to 5.5 V	Full	0.7 V+			V
Low Level Input Voltage	V_{SI}		1.65 to 1.95 V	Full			0.25 V+	· •
Low Level Input Voltage	- SL	V+ :	= 2.3 to 5.5 V	Full			0.3 V+	
			$V_{BN} = 0 \text{ V}, I_{A} = 30 \text{ mA}$	Full		6	7	
		V+ = 4.5 V	$V_{BN} = 2.3 \text{ V}, I_{A} = -30 \text{ mA}$	Full		6	12	
			$V_{BN} = 4.5 \text{ V}, I_{A} = -30 \text{ mA}$	Full		9	15	
		V+ = 3.0 V	$V_{BN} = 0 \text{ V}, I_{A} = 24 \text{ mA}$	Full		8	9	1
On Resistance	R _{ON}	V + = 3.0 V	$V_{BN} = 3.0 \text{ V}, I_{A} = -24 \text{ mA}$	Full		12	20	
		V+ = 2.3 V	$V_{BN} = 0 \text{ V, } I_A = 8 \text{ mA}$	Full		9	12	Ω
			$V_{BN} = 2.3 \text{ V}, I_A = -8 \text{ mA}$	Full		13	30	
		V+ = 1.65 V	$V_{BN} = 0 \text{ V, } I_{A} = 4 \text{ mA}$	Full		12	20	
			V _{BN} = 1.8 V, I _A = - 4 mA	Full		18	50	
	R _{FLAT}	0 < V _{BN} < V+	$V+ = 4.5 \text{ V}, I_A = -30 \text{ mA}$	Room		6		
On Desistance Flateres			V+ = 3.0 V, I _A = - 24 mA	Room		12		
On Resistance Flatness			V+ = 2.3 V, I _A = - 8 mA	Room		22		
			V+ = 1.65 V, I _A = - 4 mA	Room		90		
	ΔR _{ON}	V+ = 4.5 V, V _{BN} = 3.15 V, I _A = - 30 mA		Room		0.32		
On Resistance Matching Between Channels		V+ = 3.0 V, V _{BN} = 2.1 V, I _A = - 24 mA		Room		0.31		
		$V+ = 2.3 \text{ V}, V_{BN} = 1.6 \text{ V}, I_A = -8 \text{ mA}$		Room		0.30		1
		V+ = 1.65 V, V _{BN} = 1.15 V, I _A = - 4 mA		Room		0.29		
Input Leakage Current	I _S	$V + = 5.5 \text{ V}, V_{\Lambda} = 5.5 \text{ V}$		Room	- 0.1		0.1	
1		5	n .	Full	- 1.0		- 1.0	
Off Stage Switch Leakage	I _{BN(off)}	$V+ = 5.5 \text{ V}, V_A/V_B = 0 \text{ V}/5.5 \text{ V}$		Room Full	- 0.1 - 1.0		0.1 - 1.0	μΑ
On State Switch Leakage	I _{BN(on)}	V+ = 5.5 V, V _A /V _B = 0 V/5.5 V		Room	- 0.1 - 1.0		0.1	





SPECIFICATIONS								
		Test Conditions Unless Otherwise Specified $V+=3.0 \text{ V, } V_S=0.25 \text{ V to } 0.7 \text{ V+}^e$			Limits			
				_ a		°C to 85		
Parameter Power Supply	Symbol	v+ = 3.0 v, v _S = 0	1.25 V 10 U.7 V+°	Temp. ^a	Min. ^b	Typ. ^c	Max.b	Unit
Power Supply Range	V+			Full	1.65	I	5.5	V
		V 55.V.V \	, ₁ , ₀ , ₀ , ₀	Room	1.00		1	-
Quiescent Supply Current	l+	$V+ = 5.5 V, V_A = V$	/ _B = V+ or GND	Full			10	μΑ
AC Electrical Characteristice								
			V+ = 1.65 to 1.95 V	Full				
Prop Delay Time ^f	t _{PHL} /t _{PLH}	V _A = 0 V	V+ = 2.3 to 2.7 V	Full		1.2		
Trop Bolay Time	1112121	Α	V+ = 3.0 to 3.6 V	Full		8.0		
			V+ = 4.5 to 5.5 V	Full		0.3		
			V+ = 1.65 to 1.95 V	Room Full		10.2 10.4		
Output Enable Time ^f	t _{PZL} /t _{PZH}	$V_{LOAD} = 2 \times V_{+}$ for t_{PZL} $V_{LOAD} = 0 V$ for t_{PZH}	V+ = 2.3 to 2.7 V	Room Full		5.9 6.2		
	'PZL/'PZH		V+ = 3.0 to 3.6 V	Room Full		4.1 4.5		
			V+ = 4.5 to 5.5 V	Room Full		2.6 2.9		ns
Output Disable Time ^f		$V_{LOAD} = 2 \times V + \text{ for } t_{PLZ}$ $V_{LOAD} = 0 \text{ V for } t_{PHZ}$	V+ = 1.65 to 1.95 V	Room Full		10.2 10.4		
			V+ = 2.3 to 2.7 V	Room		5.9 6.2		
	t _{PLZ} /t _{PHZ}		V+ = 3.0 to 3.6 V	Room		4.1		
			V+ = 4.5 to 5.5 V	Room		4.5 2.6 2.9		
		V+ = 1.65 to 1.95 V		Full	0.5			
		V+ = 2.3 to 2.7 V		Full	0.5			
Break-Before-Make Time ^d	t _{BBM}	V+ = 3.0 to 3.65		Full	0.5			
		V+ = 4.5 to 5.5 V		Full	0.5			
d		C _L = 0.1 nF, V _{GEN} = 0 V	V+ = 5 V	Room		7		
Charge Injection ^d	Q	$R_{GEN} = 0 \Omega$	V+ = 3.3 V	Room		3		pC
Analog Switch Characteristics								
Off Isolation ^d	OIRR	$R_L = 50 \Omega$, f	= 10 MHz	Room		- 57.6		dB
Crosstalk ^d	X _{TALK}	_		Room		- 58.7		ub
- 3 db Bandwidth ^d	BW	$R_L = 50 \Omega$		Room		> 250		MHz
Capacitance								
Control Pin Capacitance ^d	C _{IN}	V+ =	0 V	Room		4.9		
B Port Off Capacitance ^d	C _{IO-B}			Room		< 6.5		nE
A Port Capacitance When Switch Enable ^d	C _{IO-A(on)}	V+ =	5 V	Room		< 18.5		pF

Notes:

- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Guaranteed by design and not production tested. The bus switch propagation delay is a function of the RC time constant contributed by the on-resistance and the specified load capacitance with an ideal voltage source (zero output impedance) driving the switch.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Vishay Siliconix



LOGIC DIAGRAM Positive Logic

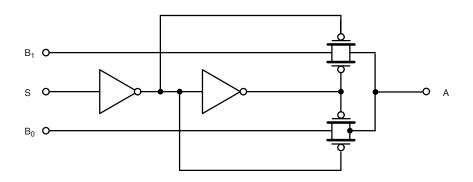
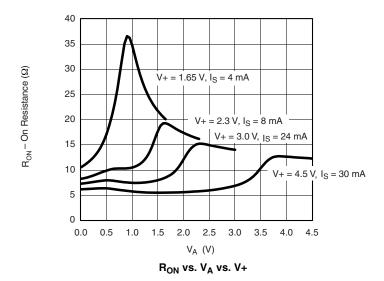


Figure 1.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





AC LOADING AND WAVEFORMS

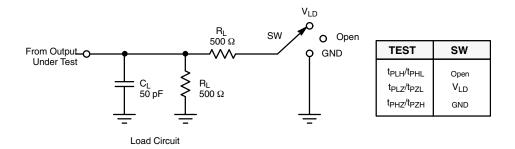


Figure 2. AC Test Circuit

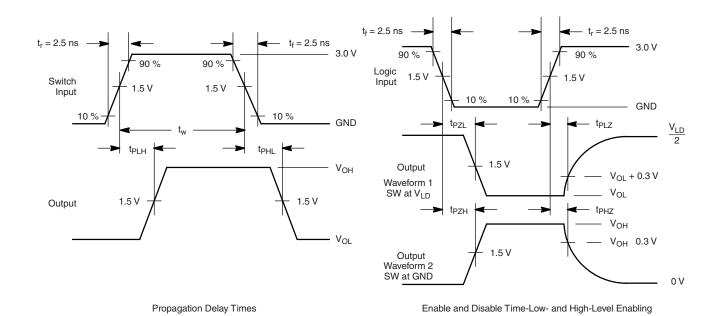


Figure 3. AC Waveforms

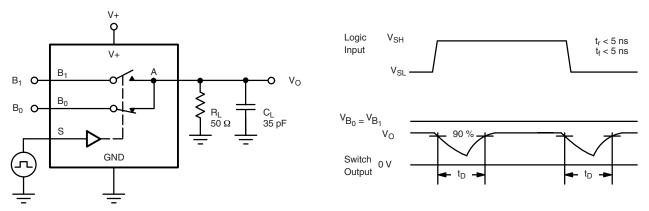
Notes

- \bullet \mathbf{C}_{L} includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 $\Omega.$
- The outputs are measured one at a time with one transition per measurement.
- t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- t_{PZL} and t_{PZH} are the same as t_{dis}.
- \bullet t_{PLH} and t_{PHL} are the same as $t_{\text{dis}}.$
- $V_{LD} = 2 V+$.

Vishay Siliconix

VISHAY

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

Figure 4. Break-Before-Make Interval

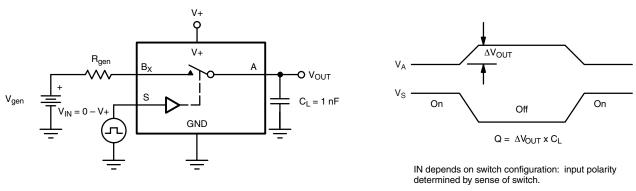


Figure 5. Charge Injection

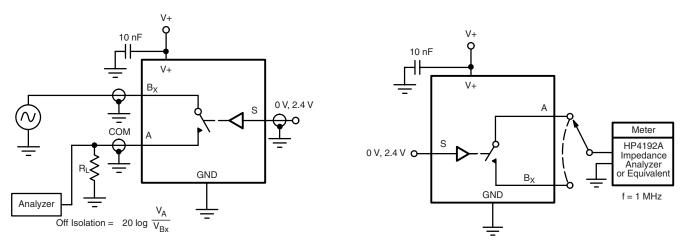


Figure 6. Off-Isolation

Figure 7. Channel Off/On Capacitance

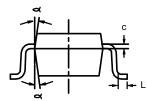
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72648.





SC-70: 6-LEADS





	MIL	LIMET	ERS	I	S		
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.90	-	1.10	0.035	_	0.043	
A ₁	-	-	0.10	-	-	0.004	
A ₂	0.80	-	1.00	0.031	_	0.039	
b	0.15	-	0.30	0.006	-	0.012	
С	0.10	-	0.25	0.004	-	0.010	
D	1.80	2.00	2.20	0.071	0.079	0.087	
Е	1.80	2.10	2.40	0.071	0.071 0.083 (
E ₁	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65BSC 0.026BSC					;	
e ₁	1.20	1.30	1.40	0.047	0.051	0.055	
L	0.10	0.20	0.30	0.004	0.008	0.012	
9	7°Nom 7°Nom						
ECN: S-03946—Rev. B, 09-Jul-01							

DWG: 5550



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.